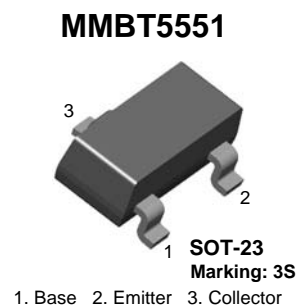
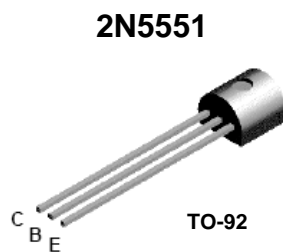


# 2N5551 / MMBT5551

## NPN General Purpose Amplifier

### Features

- This device is designed for general purpose high voltage amplifiers and gas discharge display drivers.
- Suffix “-C” means Center Collector in 2N5551 (1. Emitter 2. Collector 3. Base)
- Suffix “-Y” means  $h_{FE}$  180~240 in 2N5551 (Test condition :  $I_C = 10\text{mA}$ ,  $V_{CE} = 5.0\text{V}$ )



### Absolute Maximum Ratings \* $T_A = 25^\circ\text{C}$ unless otherwise noted

| Symbol         | Parameter                        | Value       | Units            |
|----------------|----------------------------------|-------------|------------------|
| $V_{CEO}$      | Collector-Emitter Voltage        | 160         | V                |
| $V_{CBO}$      | Collector-Base Voltage           | 180         | V                |
| $V_{EBO}$      | Emitter-Base Voltage             | 6.0         | V                |
| $I_C$          | Collector current - Continuous   | 600         | mA               |
| $T_J, T_{stg}$ | Junction and Storage Temperature | -55 to +150 | $^\circ\text{C}$ |

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

1. These ratings are based on a maximum junction temperature of 150 degrees C.
2. These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Thermal Characteristics $T_A=25^\circ\text{C}$ unless otherwise noted

| Symbol          | Parameter                               | Max    |           | Units                     |
|-----------------|---|--------|-----------|---------------------------|
|                 |   | 2N5551 | *MMBT5551 |                           |
| $P_D$           | Total Device Dissipation                | 625    | 350       | mW                        |
|                 | Derate above $25^\circ\text{C}$         | 5.0    | 2.8       | mW/ $^\circ\text{C}$      |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case    | 83.3   |           | $^\circ\text{C}/\text{W}$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 200    | 357       | $^\circ\text{C}/\text{W}$ |

\* Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06."

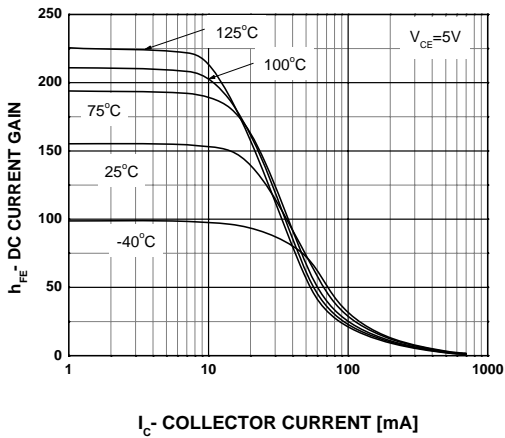
**Electrical Characteristics**  $T_A = 25^\circ\text{C}$  unless otherwise noted

| Symbol                              | Parameter                             | Test Condition   | Min.           | Max.         | Units               |
|-------------------------------------|---------------------------------------|--|----------------|--------------|---------------------|
| <b>Off Characteristics</b>          |                                       |  |                |              |                     |
| $V_{(BR)CEO}$                       | Collector-Emitter Breakdown Voltage * | $I_C = 1.0\text{mA}, I_B = 0$  | 160            |              | V                   |
| $V_{(BR)CBO}$                       | Collector-Base Breakdown Voltage      | $I_C = 100\mu\text{A}, I_E = 0$  | 180            |              | V                   |
| $V_{(BR)EBO}$                       | Emitter-Base Breakdown Voltage        | $I_E = 10\mu\text{A}, I_C = 0$   | 6.0            |              | V                   |
| $I_{CBO}$                           | Collector Cutoff Current              | $V_{CB} = 120\text{V}, I_E = 0$<br>$V_{CB} = 120\text{V}, I_E = 0, T_A = 100^\circ\text{C}$  |                | 50<br>50     | nA<br>$\mu\text{A}$ |
| $I_{EBO}$                           | Emitter Cutoff Current                | $V_{EB} = 4.0\text{V}, I_C = 0$  |                | 50           | nA                  |
| <b>On Characteristics</b>           |                                       |  |                |              |                     |
| $h_{FE}$                            | DC Current Gain                       | $I_C = 1.0\text{mA}, V_{CE} = 5.0\text{V}$<br>$I_C = 10\text{mA}, V_{CE} = 5.0\text{V}$<br>$I_C = 50\text{mA}, V_{CE} = 5.0\text{V}$ | 80<br>80<br>30 | 250          |                     |
| $V_{CE(sat)}$                       | Collector-Emitter Saturation Voltage  | $I_C = 10\text{mA}, I_B = 1.0\text{mA}$<br>$I_C = 50\text{mA}, I_B = 5.0\text{mA}$   |                | 0.15<br>0.20 | V<br>V              |
| $V_{BE(sat)}$                       | Base-Emitter On Voltage               | $I_C = 10\text{mA}, I_B = 1.0\text{mA}$<br>$I_C = 50\text{mA}, I_B = 5.0\text{mA}$   |                | 1.0<br>1.0   | V<br>V              |
| <b>Small Signal Characteristics</b> |                                       |  |                |              |                     |
| $f_T$                               | Current Gain Bandwidth Product        | $I_C = 10\text{mA}, V_{CE} = 10\text{V},$<br>$f = 100\text{MHz}$   | 100            |              | MHz                 |
| $C_{obo}$                           | Output Capacitance                    | $V_{CB} = 10\text{V}, I_E = 0, f = 1.0\text{MHz}$  |                | 6.0          | pF                  |
| $C_{ibo}$                           | Input Capacitance                     | $V_{BE} = 0.5\text{V}, I_C = 0, f = 1.0\text{MHz}$   |                | 20           | pF                  |
| $H_{fe}$                            | Small-Signal Current Gain             | $I_C = 1.0\text{mA}, V_{CE} = 10\text{V}, f = 1.0\text{kHz}$   | 50             | 250          |                     |
| NF                                  | Noise Figure                          | $I_C = 250\mu\text{A}, V_{CE} = 5.0\text{V},$<br>$R_S = 1.0\text{k}\Omega, f = 10\text{Hz to } 15.7\text{kHz}$                       |                | 8.0          | dB                  |

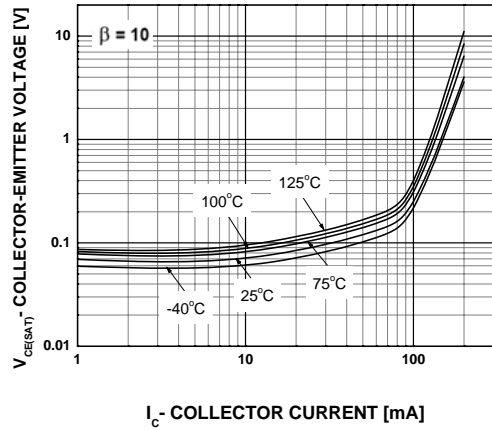
**Spice Model**

NPN (Is=2.511f Xti=3 Eg=1.11 Vaf=100 Bf=242.6 Ne=1.249 Ise=2.511f Ikf=.3458 Xtb=1.5 Br=3.197 Nc=2 Isc=0 Ikr=0 Rc=1 Cjc=4.883p Mjc=.3047 Vjc=.75 Fc=.5 Cje=18.79p Mje=.3416 Vje=.75 Tr=1.202n Tf=560p Itf=50m Vtf=5 Xtf=8 Rb=10)

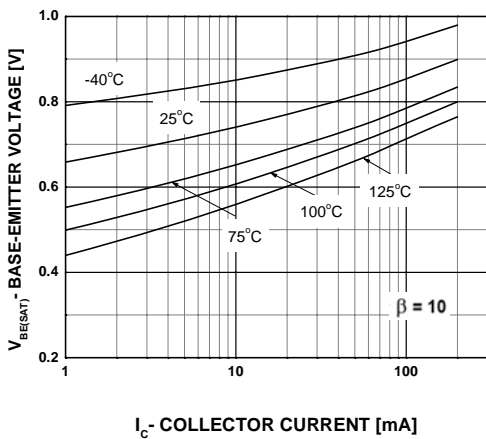
## Typical Performance Characteristics



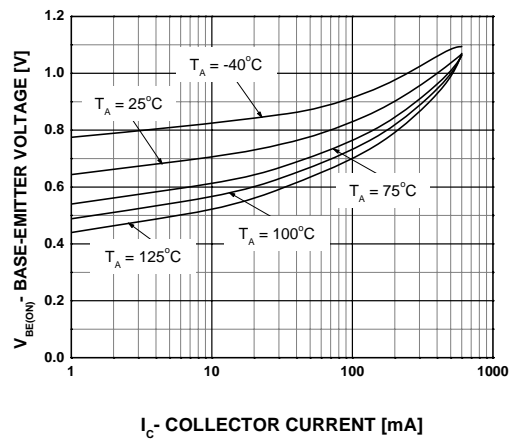
**Figure 1. Typical Pulsed Current Gain vs Collector Current**



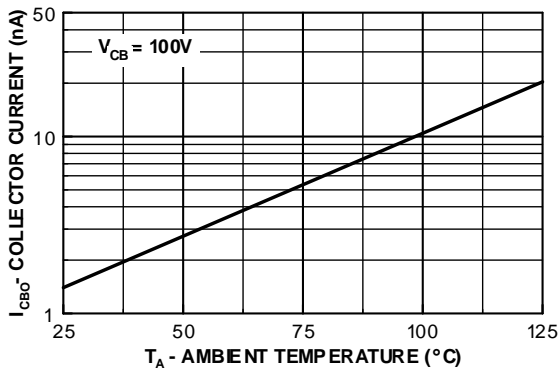
**Figure 2. Collector-Emitter Saturation Voltage vs Collector Current**



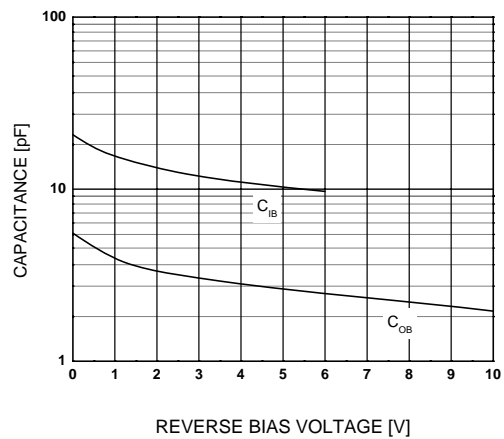
**Figure 3. Base-Emitter Saturation Voltage vs Collector Current**



**Figure 4. Base-Emitter On Voltage vs Collector Current**



**Figure 5. Collector Cutoff Current vs Ambient Temperature**



**Figure 6. Input and Output Capacitance vs Reverse Voltage**

Typical Performance Characteristics (Continued)

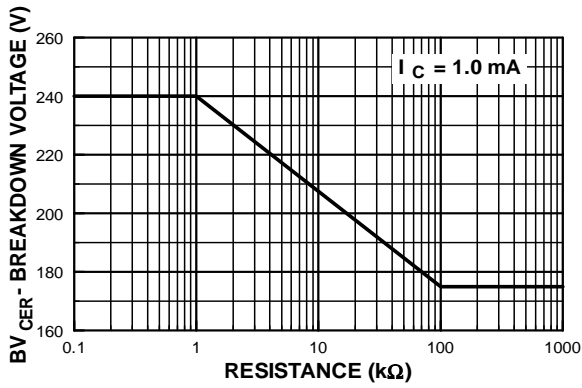


Figure 7. Collector- Emitter Breakdown Voltage with Resistance Between Emitter-Base

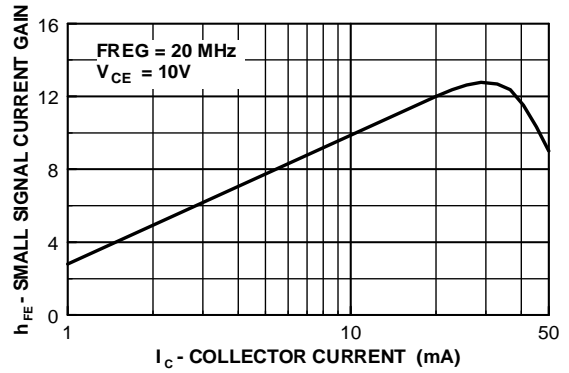


Figure 8. Small Signal Current Gain vs Collector Current

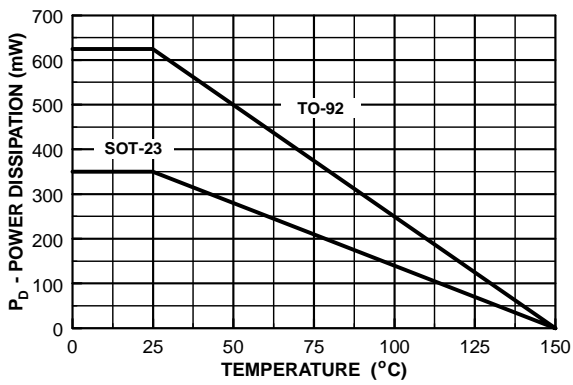





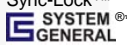


Figure 7. Power Dissipation vs Ambient Temperature



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Rev. 140



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